







	<h2>RSH070P05GZETB</h2>
	<p><b>Hersteller-Teilenummer:</b> RSH070P05GZETB</p> <hr/> <p><b>Hersteller / Marke:</b> LAPIS Semiconductor</p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 45V 7A SOP8</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">RSH070P05GZETB.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 2500 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	RSH070P05GZETB
Hersteller	LAPIS Semiconductor
Beschreibung	MOSFET P-CH 45V 7A SOP8
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	2500 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-SOIC (0.154", 3.90mm Width)
Supplier Device-Gehäuse	8-SOP
Verlustleistung (max)	2W (Ta)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	45V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	7A (Ta)
Rds On (Max) @ Id, Vgs	27 mOhm @ 7A, 10V
VGS (th) (Max) @ Id	2.5V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	47.6nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	4100pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

RSH070P05GZETB ist neu im Original, Suche RSH070P05GZETB Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie RSH070P05GZETB LAPIS Semiconductor mit Garantie und Vertrauen. Anfrage RSH070P05GZETB: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>RSH070N05TB1</b> LAPIS Semiconductor MOSFET N-CH 45V 7A SOP8</p>	 <p><b>RSH070N05</b> ROHM RSH070N05 ROHM</p>	 <p><b>RSH070N05TB</b> R RSH070N05TB R</p>	 <p><b>RSH070N05GZETB</b> LAPIS Semiconductor MOSFET N-CH 45V 7A SOP8</p>
 <p><b>RSH090N03TB</b> ROHM RSH090N03TB ROHM</p>	 <p><b>RSH070P05TB1</b> LAPIS Semiconductor MOSFET P-CH 45V 7A SOP8</p>	 <p><b>RSH0E391MCN1GB</b> Nichicon CAP ALUM POLY 390UF 20% 2.5V SMD</p>	 <p><b>RSH070P05TB</b> ROHM RSH070P05TB ROHM</p>

### heiße Teile

Mehr

111MT020KB	18125C334KAT2A	1SMA5934BT3G	D 2MBI1400VXB-170-54	A1020B-PL44I
ABA-54563	ADC10154CIWMX/NOPB	ADM2486BRWZ	ADM666AR	BCM3517KQLG
BD2066FJ-E2	BGS1414MC18-2E6433	C2012X6S1H335M125AC	CC0805JKNPO0BN222	CC1206JRNPOBBN681
D GRM155R61A105KE01J	GRM2197U2A241JZ01D	HFBR-1521ETZ	IRKJ41/04	IS24C02B-2ZLI
L-07C3N3SV6T	LM4050CIM3X-1.5	LTC1624CS8	MIC2211-PPBMLTR	NE25139T1U72
PH300F280-12	RA201048XX00	RB056L-40TFTE25	RB068LAM-100TR	RSH065N03TB
RSH065N03TB1	D RSH065N06	RSH065N06TB	RSH065N06TB1	RSH070N05TB
RSH070N05TB1	RSH070P05TB	RSH070P05TB1	RSH090N03TB	RSH090N03TB1
RSH100N03TB	RSH100N03TB1	RSH110N03TB	D RSH110N03TB1	RSH125N03TB
RSH125N03TB1	RSH140N03TB	S-80834ANMP-EDY-T2-E1	S-8233AGFT-TB	TC74AC112F

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited